GTM

GJ1116

0.6A Low Dropout Positive Adjustable or Fixed-Mode Regulator

Description

The GJ1116 is a low dropout at positive adjustable or fixed-mode regulator with minimum of 0.6A output current capability. The product is specifically designed to provide well-regulated supply for low voltage IC applications such as high-speed bus termination and low current 3.3V logic supply. GJ1116 is also well suited for other applications such as VGA cards. GJ1116 is guaranteed to have lower than 1.3V dropout at full load current making it ideal to provide well regulated outputs of 1.25V to 5.0V with up to 12V input supply.

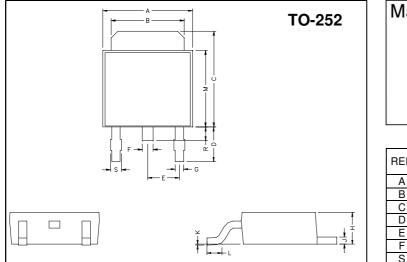
Features

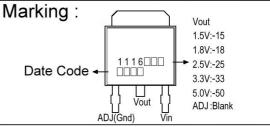
- 1.3Vmaximum dropout full load current
- Fast transient response
- Output current limiting
- Built-in thermal shutdown
- Good noise rejection
- 3-Terminal Adjustable or Fixed 1.5V,1.8V,2.5V,3.3V,5.0V

Applications

- PC peripheral
- Communication

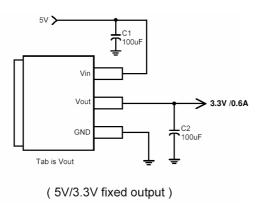
Package Dimensions

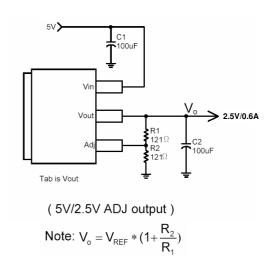




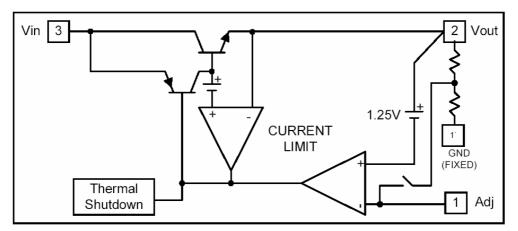
REF.	Millimeter		REF.	Millimeter		
	Min.	Max.	ΠLΙ.	Min.	Max.	
Α	6.40	6.80	G	0.50	0.70	
В	5.20	5.50	Н	2.20	2.40	
С	6.80	7.20	J	0.45	0.55	
D	2.40	3.00	K	0	0.15	
E	2.30 REF.		L	0.90	1.50	
F	0.70	0.90	М	5.40	5.80	
S	0.60	0.90	R	0.80	1.20	

Typical Circuit





Block Diagram



Pin Descriptions

Name	I/O	Pin#	Function		
Adj (GND)		1	A resistor divider from this pin to the Vout pin and ground sets the output voltage (Ground only for fixed mode)		
Vout	0	2	The output of the regulator. A minimum of 10uF capacitor ($0.15\Omega \le ESR \le 20\Omega$) must be connected from this pin to ground to insure stability.		
Vin	I	3	The input pin of regulator. Typically a large storage capacitor $(0.15\Omega \le ESR \le 20\Omega)$ is connected from this pin to ground to insure that the input voltage does not sag below the minimum dropout voltage during the load transient response. This pin must always be 1.3V higher than Vout in order for the device to regulate properly.		

Absolute Maximum Ratings

Symbol	Parameter	Ratings	Unit	
Vin	DC Supply Voltage	-0.3 to 12	V	
PD	Power Dissipation	Internally Limited		
Tst	Storage Temperature	-65 ~ + 150	°C	
Тор	Operating Junction Temperature Range	0 ~ + 150	°C	

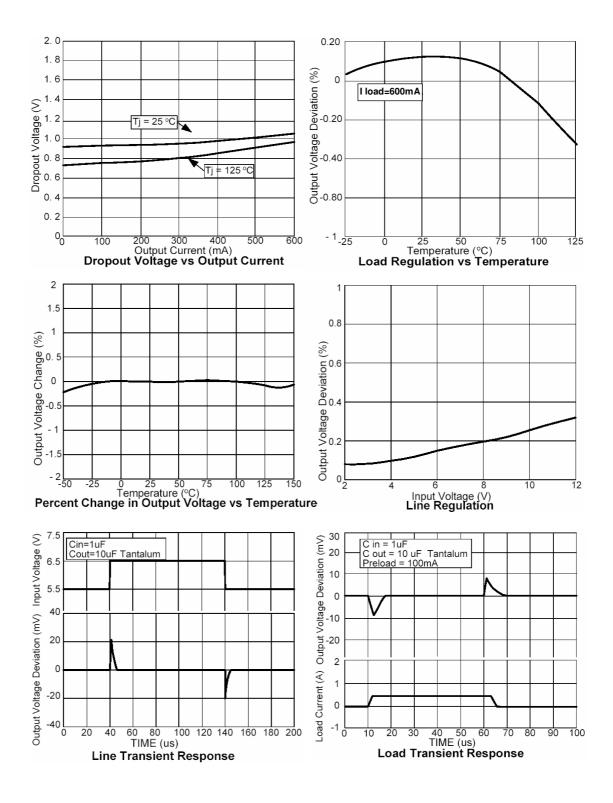
Electrical Characteristics

Parameter	Parameter Conditions		Min	Тур	Max	Unit
Reference Voltage	GJ1116ADJ	Io=10mA, Tj=25°C, (VIN-Vout)=1.5V	1.225	1.250	1.275	V
	GJ1116-1.5	lo=10mA, Tj=25°C, 3.0V≤ Vin ≤12V	1.470	1.500	1.530	V
	GJ1116-1.8	lo=10mA, TJ=25°C, 3.3V≤ Vเℕ ≤12V	1.764	1.800	1.836	V
Output Voltage	GJ1116-2.5	lo=10mA, TJ=25°C, 4.0V≤ VIN ≤12V	2.450	2.500	2.550	V
	GJ1116-3.3	lo=10mA, Tj=25℃, 4.8V≤ Vin ≤12V	3.235	3.300	3.365	V
	GJ1116-5.0	lo=10mA, TJ=25°C, 6.5V≤ Vเℕ ≤12V	4.900	5.000	5.100	V
Line Regulation	GJ1116-XXX	Io=10mA, Vout+1.5V< Vin <12V, Tj=25℃	-	-	0.2	%
	GJ1116ADJ	VIN=3.3V, Vadj=0, 0mA< lo <0.6A, TJ=25℃ (Note 1,2)	-	-	1	%
	GJ1116-1.5	VIN=3.0V, 0mA< lo <0.6A, TJ=25 $^\circ\!\mathbb{C}$ (Note 1,2)	-	12	15	mV
Load Regulation	GJ1116-1.8	VIN=3.3V, 0mA< lo <0.6A, TJ=25 $^\circ\!\mathrm{C}$ (Note 1,2)	-	15	18	mV
	GJ1116-2.5	VIN=4.0V, 0mA< lo <0.6A, TJ=25 $^\circ\!\mathrm{C}$ (Note 1,2)	-	20	25	mV
	GJ1116-3.3	VIN=5.0V, 0mA< Io <0.6A, TJ=25°C (Note 1,2)	-	26	33	mV
	GJ1116-5.0	VIN=8.0V, 0mA< Io <0.6A, TJ=25°C (Note 1,2)	-	40	50	mV
Dropout Voltage (Vім-Vouт)	GJ1116-XXX	Io=0.6A (Δ Vout =0.1% Vout)	-	1.1	1.3	v
Current Limit	GJ1116-XXX	Vin-Vout=5V	0.7	-	-	А
Minimum Load Current	Adjustable model	Vin=5V	-	5	10	mA
Adjust Pin Current	Adjustable model	Vin=12V, Io=10mA	-	50	100	uA
Quiescent Current	fixed model	Vin=12V, Io=0mA	-	-	12	mA
Thermal Regulation	Ta=25°C,30ms pulse		-	0.008	0.04	%/W
Divale Dejection	F=120Hz, Cout=25uF Tantalum, Iout=0.6A			•		
Ripple Rejection	GJ1116-XXX	VIN=VOUT+3V	-	60	70	dB
Temperature Stability	Io=10mA		-	0.5	-	%
θJA Thermal Resistance Junction-to-Ambient(No heat sink ;No air flow)			-	92	-	°C/W
θJC Thermal Resistance Junction-to-Case	Control Circuitry/Power Transistor		-	10	-	°C/W

Note 1: See thermal regulation specifications for changes in output voltage due to heating effects. Line and load regulation are measured at a constant junction temperature by low duty cycle pulse testing. Load regulation is measured at the output lead =1/18" from the package.

Note 2: Line and load regulation are guaranteed up to the maximum power dissipation of 15W. Power dissipation is determined by the difference between input and output and the output current. Guaranteed maximum power dissipation will not be available over the full input/output range.

Characteristics Curve



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Head Office And Factory:
Taiwan: No. 17-1 Tatung Rd. Fu Kou Hsin-Chu Industrial Park, Hsin-Chu, Taiwan, R. O. C.
TEL: 886-3-597-7061 FAX: 886-3-597-9220, 597-0785
China: (201203) No.255, Jang-Jiang Tsai-Lueng RD., Pu-Dung-Hsin District, Shang-Hai City, China.
TEL: 86-21-5895-7671 ~ 4 FAX: 86-21-38950165